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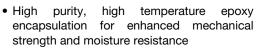
High Performance Schottky Rectifier, 2 x 10 A



PRIMARY CHARACTERISTICS							
I _{F(AV)}	2 x 10 A						
V _R	80 V, 90 V, 100 V						
V _F at I _F	0.70 V						
I _{RM} max.	6 mA at 125 °C						
T _J max.	150 °C						
E _{AS}	24 mJ						
Package	TO-220AB 3L						
Circuit configuration	Common cathode						

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- · High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform (per device)	20	А						
I _{FRM}	T _C = 133 °C per leg	20	А						
V _{RRM}		80/100	V						
I _{FSM}	t _p = 5 μs sine	850	А						
V _F	10 A _{pk} , T _J = 125 °C	0.70	V						
T _J	Range	-65 to +150	°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	MBR2080CT-M3	MBR2090CT-M3	MBR20100CT-M3	UNITS				
Maximum DC reverse voltage	80	90	100	W					
Maximum working peak reverse voltage	V_{RWM}	60	90	100	V				

ABSOLUTE MAXIMUM RATINGS									
PARAMETER		SYMBOL	TEST CON	VALUES	UNITS				
Maximum average	oer leg	$I_{F(AV)}$ $I_{C} = 133 ^{\circ}\text{C}$, rated V_{R}		10					
forward current	er device			20					
Peak repetitive forward current per leg		I _{FRM}	Rated V _R , square wave, 20 kHz, T _C = 133 °C		20				
Non-repetitive peak surge current		I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	850	Α			
			Surge applied at rated load conditions halfwave, single phase, 60 Hz		150				
Peak repetitive reverse surge	current	I _{RRM}	2.0 μs, 1.0 kHz		0.5				
Non-repetitive avalanche ener	rgy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 12	mH	24	mJ			

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CON	TEST CONDITIONS					
		10 A	T _{.1} = 25 °C	0.80				
Maximum forward voltage drop	V _{FM} ⁽¹⁾	20 A	1j=25 C	0.95	V			
Maximum forward voltage drop	V _{FM} (··)	10 A	T 105 °C	0.70				
		20 A	T _J = 125 °C	0.85				
Maximum instantaneous reverse current	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.10	mA			
iviaximum instantaneous reverse current		T _J = 125 °C	hated DC voltage	6				
Threshold voltage	V _{F(TO)}	$T_J = T_J$ maximum		0.433	V			
Forward slope resistance	r _t			15.8	mΩ			
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal rang	400	pF				
Typical series inductance	L _S	Measured from top of termi	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs				

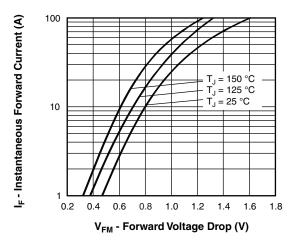
Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction temper	erature range	TJ		-65 to +150	°C			
Maximum storage tempe	rature range	T _{Stg}		-65 to +175				
Maximum thermal resista junction to case per leg	ance,	R _{thJC}	DC operation	2.0				
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased (Only for TO-220)	0.50 °C				
Maximum thermal resista junction to ambient	Maximum thermal resistance, junction to ambient		DC operation (For D ² PAK and TO-262)	50				
Approximate weight				2	g			
Approximate weight				0.07	oz.			
Mounting torque	minimum			6 (5)	kg∙ cm			
Mounting torque	maximum			12 (10)	(lbf \cdot in)			
Marking device			Case style TO-220AB 3L	MBR20 MBR20 MBR20	090CT			

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100 I_R - Reverse Current (mA) 10 T₁ = 125 °C 0.1 0.01 0.001 T_J = 25 °C 0.0001 20 0 40 60 80 100 V_R - Reverse Voltage (V)

Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

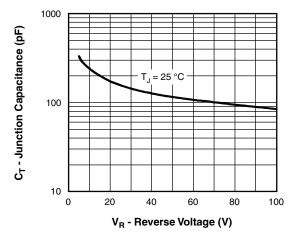


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

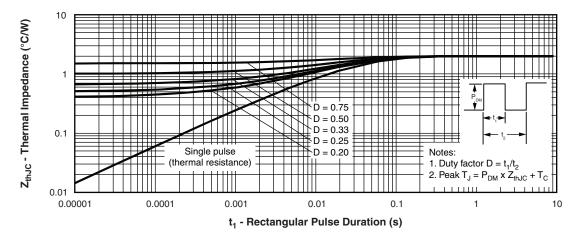


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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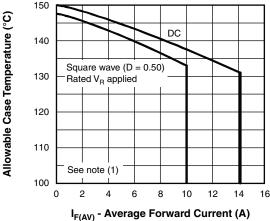


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current (Per Leg)

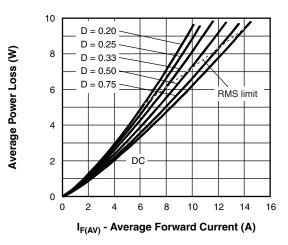


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

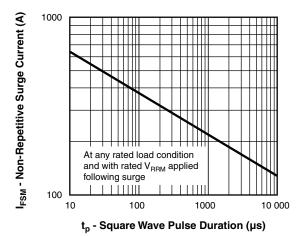


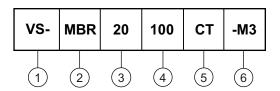
Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

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ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

Schottky MBR series

Current rating (20 = 20 A)

080 = 80 V

Voltage ratings

090 = 90 V

CT = essential part number

100 = 100 V

Environmental digit

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION							
VS-MBR2080CT-M3	50	Antistatic plastic tubes							
VS-MBR2090CT-M3	50	Antistatic plastic tubes							
VS-MBR20100CT-M3	50	Antistatic plastic tubes							

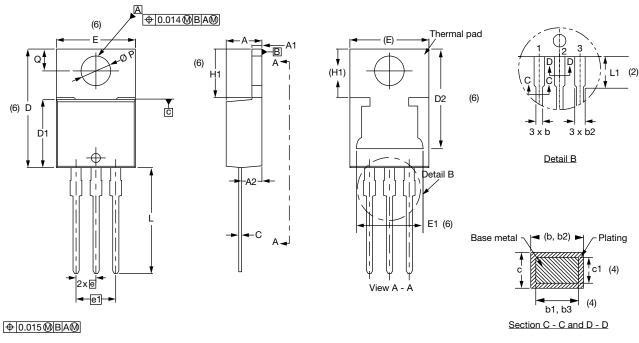
LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?96154					
Part marking information	www.vishay.com/doc?95028					



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TO-220AB 3L

DIMENSIONS in millimeters and inches



Lead tip \	
	1

Conforms to JEDEC® outline TO-220AB

SYMBOL	MILLIMETERS		INCHES		NOTES	NOTES		TEC .	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	STMBOL	MIN.	MAX.		MIN.	MAX.	NOTES			
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7			
A1	1.14	1.40	0.045	0.055			E	10.11	10.51	0.398	0.414	3, 6			
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6			
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105				
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208				
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6			
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552				
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2			
с1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154				
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118				
D1	8.38	9.02	0.330	0.355											

Notes

- $^{(1)}$ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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